**OT407** 

Four-quadrant triac, enhanced noise immunityRev. 01 — 19 May 2008P

Product data sheet

## 1. Product profile

## 1.1 General description

Passivated sensitive gate triac in a SOT54A (wide pitch) plastic package

#### 1.2 Features

- Sensitive gate Gate triggering in four quadrants Direct interfacing to logic level ICs Direct interfacing to low power gate drive circuits High blocking voltage to 800 V Enhanced immunity to voltage transients and noise **1.3 Applications** Home appliances Low power motor control Low power loads in industrial process Low power AC fan speed controllers control 1.4 Quick reference data IGT  $\leq$  5 mA V<sub>DRM</sub> ≤ 800 V I<sub>TSM</sub>  $\leq$  12.5 A (t = 20 ms) I<sub>GT</sub>  $\leq$  7 mA (T2–G+)
- **Pinning information** 2.

I  $I_{T(RMS)} \le 1 \text{ A}$ 

Pin	Description	Simplified outline	Graphic symbol
1	main terminal 2 (T2)		<b>N</b> 1
2	gate (G)		T2-T1
3	main terminal 1 (T1)		G sym051

SOT54A



## 3. Ordering information

Table 2.         Ordering information						
Type number	Package					
	Name	Description	Version			
OT407	-	plastic single-ended leaded (through hole) package; 3 leads (wide pitch)	SOT54A			

## 4. Limiting values

#### Table 3. Limiting values

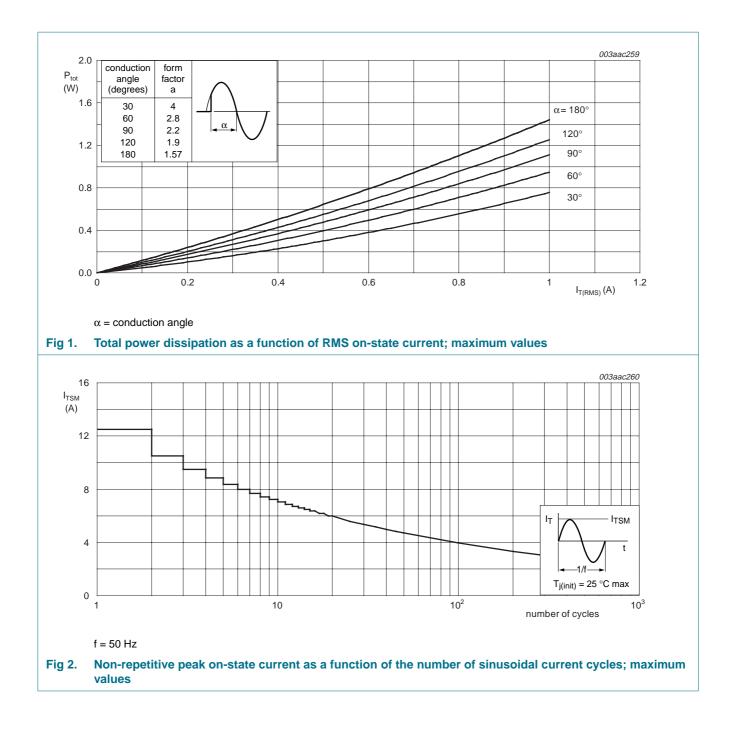
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	800	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; $T_{lead} \le 38 \text{ °C}$ ; see Figure 4 and 5	-	1	А
I <sub>TSM</sub>	non-repetitive peak on-state current	full sine wave; $T_j = 25 \text{ °C}$ prior to surge; see Figure 2 and 3			
		t = 20 ms	-	12.5	А
		t = 16.7 ms	-	13.8	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms	-	1.28	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state current	$I_{TM} = 1 \text{ A}; I_G = 20 \text{ mA};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$			
		T2+ G+	-	50	A/μs
		T2+ G–	-	50	A/μs
		T2– G–	-	50	A/μs
		T2– G+	-	10	A/μs
I <sub>GM</sub>	peak gate current		-	1	А
P <sub>GM</sub>	peak gate power		-	2	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.1	W
T <sub>stg</sub>	storage temperature		-40	+150	°C
Tj	junction temperature		-	125	°C

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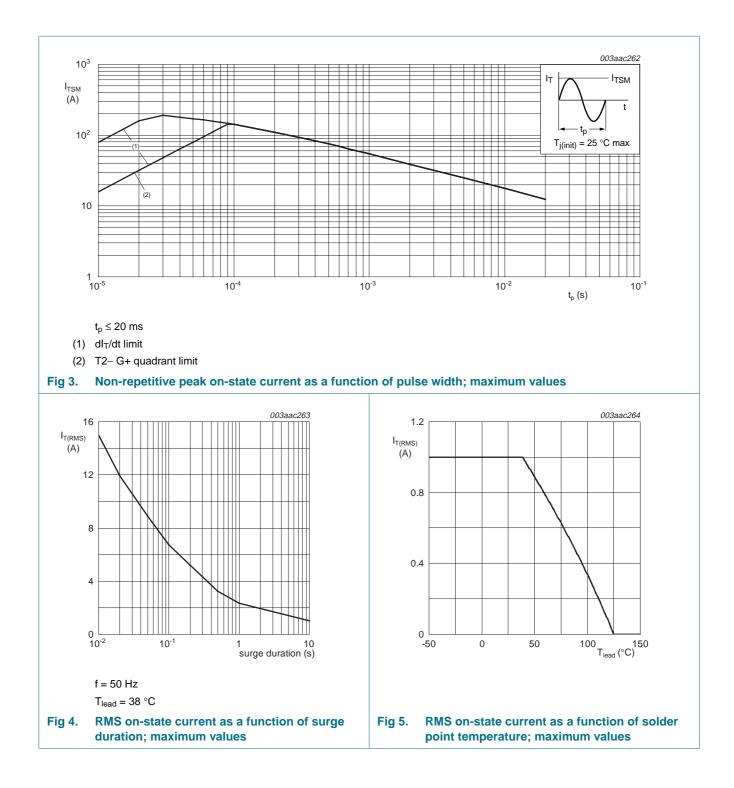
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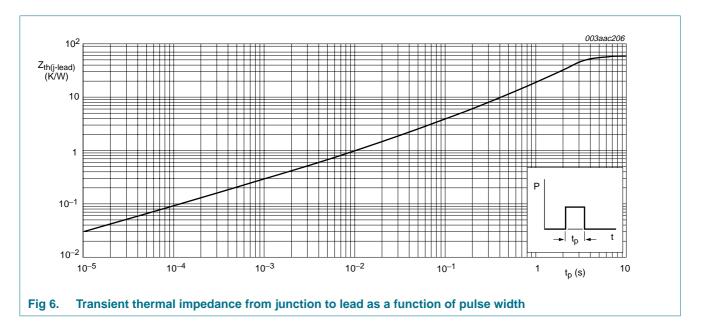
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#### **Thermal characteristics** 5.

Table 4.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th}(j-\text{lead})}$	thermal resistance from junction to lead	full cycle; see <u>Figure 6</u>	-	-	60	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	full cycle; printed-circuit board mounted; lead length = 4 mm	-	150	-	K/W



#### OT407\_1 **Product data sheet**

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## 6. Static characteristics

#### Table 5. Static characteristics

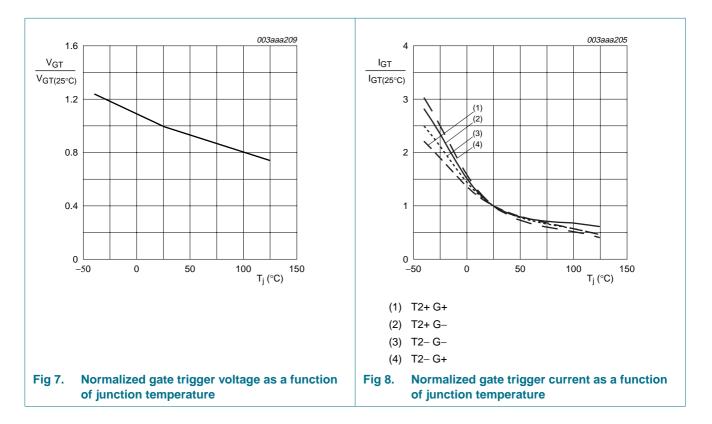
 $T_i = 25 \circ C$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 8}}{100000000000000000000000000000000000$				
		T2+ G+	0.25	-	5	mA
		T2+ G–	0.25	-	5	mA
		T2– G–	0.25	-	5	mA
		T2– G+	0.35	-	7	mA
IL latching current		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ see } \frac{\text{Figure } 10}{10}$				
		T2+ G+	-	-	10	mA
		T2+ G–	-	-	25	mA
		T2– G–	-	-	10	mA
		T2– G+	-	-	10	mA
I <sub>H</sub>	holding current	$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ see } \frac{\text{Figure } 11}{100000000000000000000000000000000$	-	-	10	mA
VT	on-state voltage	I <sub>T</sub> = 1 A; see <u>Figure 9</u>	-	1.3	1.6	V
V <sub>GT</sub> gat	gate trigger voltage	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 7}}{100000000000000000000000000000000000$	-	-	1.3	V
		$V_D = V_{DRM}; I_T = 0.1 \text{ A}; T_j = 125 ^{\circ}\text{C}$	0.2	-	-	V
I <sub>D</sub>	off-state current	$V_D = V_{DRM(max)}; T_j = 125 \ ^{\circ}C$	-	-	0.5	mA

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# 7. Dynamic characteristics

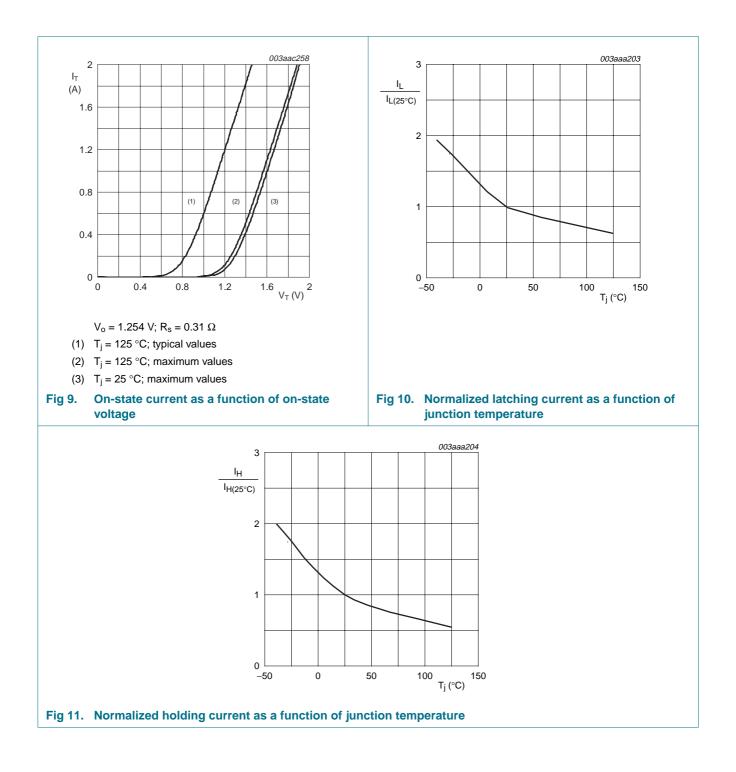
Table 6.	Dynamic characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 0.67 $V_{DRM(max)}$ ; $T_j$ = 110 °C; exponential waveform; gate open circuit	20	-	-	V/µs
dV <sub>com</sub> /dt	rate of change of commutating voltage	$V_{DM}$ = 400 V; T <sub>j</sub> = 110 °C; I <sub>TM</sub> = 1 A; dI <sub>com</sub> /dt = 0.44 A/ms	1	-	-	V/µs



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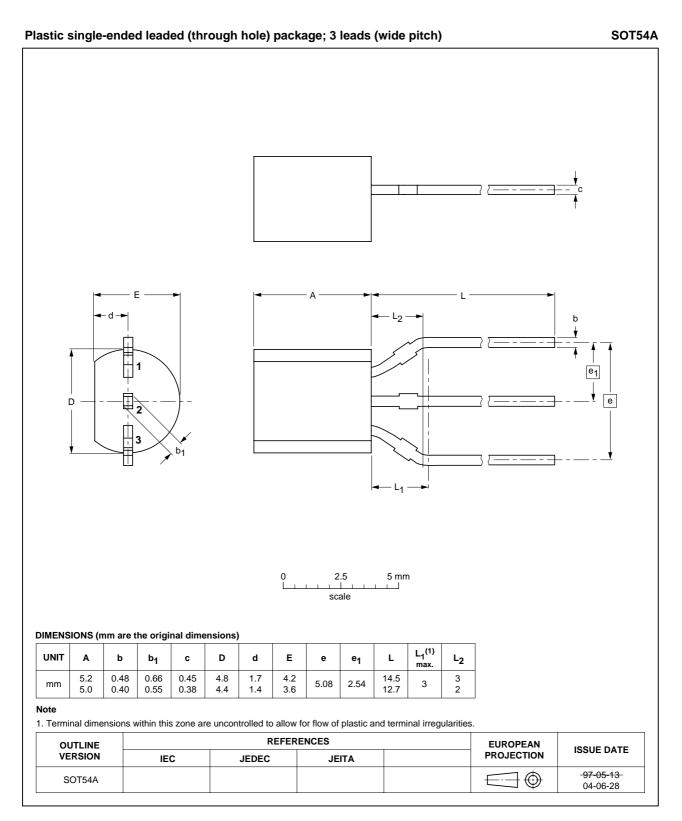
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## 8. Package outline



# Fig 12. Package outline SOT54A

# 9. Revision history

Table 7. Revision hist	Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes		
OT407_1	20080519	Product data sheet	-	-		

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Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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